CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT540AFT,74VHCT541AFT

1. Functional Description

Octal Bus Buffer
74VHCT540AFT: INVERTED, 3-STATE OUTPUTS
74VHCT541AFT: NON-INVERTED, 3-STATE OUTPUTS

2. General

The 74VHCT540AFT and 541AFT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The $74\mathrm{VHCT540AFT}$ is an inverting type and, the $74\mathrm{VHCT541AFT}$ is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

The input voltage are compatible with TTL output voltage.

These devices may be used as a level converter for interfacing $3.3~\mathrm{V}$ to $5~\mathrm{V}$ system.

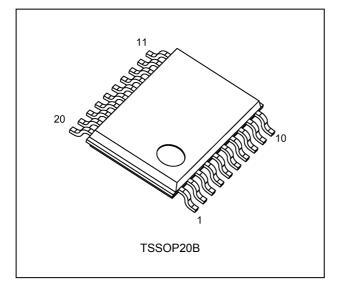
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

3. Features

- (1) High speed: Propagation delay time = 5.4 ns (typ.) at $V_{\rm CC}$ = 5 V
- (2) Quiescent supply current: I_{CC} = 4 μA (max) at T_a = 25 $^{\circ}\text{C}$
- (3) Compatible with TTL input: V_{IL} = 0.8 V(max)
 - V_{IH} = 2.0 V(min)
- (4) Power down protection is provided on all inputs and outputs.
- (5) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (6) Low noise: $V_{OLP} = 1.5 V (max)$
- (7) Pin and function compatible with the 74 series (74ACT/HCT/AHCT etc.) 540/541 type.

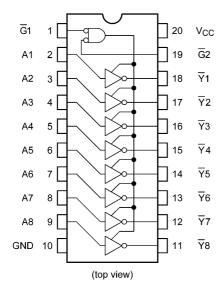
4. Packaging



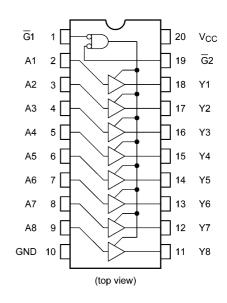
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5. Pin Assignment

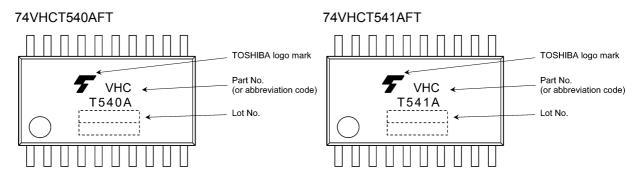
74VHCT540AFT



74VHCT541AFT

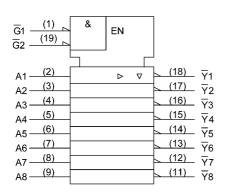


6. Marking

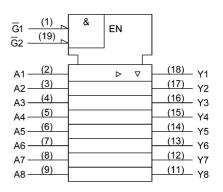


7. IEC Logic Symbol

74VHCT540AFT



74VHCT541AFT



8. Truth Table

| Input G1 | Input G2 | Input A _n | Output Y _n | Output \overline{Y}_n |
|----------|----------|----------------------|-----------------------|-------------------------|
| Н | Х | Х | Z | Z |
| Х | Н | х | Z | Z |
| L | L | Н | н | L |
| L | L | L | L | Н |

X: Don't care (L or H)

Z: High impedance

Yn: 74VHCT541AFT

Yn: 74VHCT540AFT

9. Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|---------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 7.0 | V |
| Input voltage | V _{IN} | | -0.5 to 7.0 | |
| Output voltage | V _{OUT} | (Note1) | -0.5 to 7.0 | |
| | | (Note2) | -0.5 to V _{CC} + 0.5 | |
| Input diode current | I _{IK} | | -20 | mA |
| Output diode current | Ι _{ΟΚ} | (Note3) | ±20 | |
| Output current | I _{OUT} | | ±25 | |
| V _{CC} /ground current | I _{CC} | | ±75 | |
| Power dissipation | PD | | 180 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Output in OFF state.

Note2: High (H) or Low (L) state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

10. Operating Ranges (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------|------------------|---------|----------------------|------|
| Supply voltage | V _{CC} | | 4.5 to 5.5 | V |
| Input voltage | V _{IN} | | 0 to 5.5 | |
| Output voltage | V _{OUT} | (Note1) | 0 to 5.5 | |
| | | (Note2) | 0 to V _{CC} | |
| Operating temperature | T _{opr} | | -40 to 85 | °C |
| Input rise and fall times | dt/dv | | 0 to 20 | ns/V |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.

Note1: Output in OFF state.

Note2: High (H) or Low (L) state.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25 \text{ °C}$)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Тур. | Max | Unit |
|---|------------------|---|--|---------------------|------|------|-------|------|
| High-level input voltage | V _{IH} | _ | | 4.5 to 5.5 | 2.0 | _ | _ | V |
| Low-level input voltage | V _{IL} | _ | | 4.5 to 5.5 | _ | | 0.8 | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | 4.5 | 4.40 | 4.50 | — | |
| | | | I _{OH} = -8 mA | 4.5 | 3.94 | _ | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 4.5 | _ | 0.0 | 0.1 | |
| | | | I _{OL} = 8 mA | 4.5 | _ | _ | 0.36 | |
| 3-state output OFF-state leakage current | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND | | | | _ | ±0.25 | μΑ |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | | ±0.1 | |
| Quiescent supply | I _{CC} | V _{IN} = V _{CC} or GND | V _{IN} = V _{CC} or GND | | _ | _ | 4.0 | |
| current | I _{CCT} | Per input :V _{IN} = 3.4V Other input:V _{CC} or GND | | 5.5 | | — | 1.35 | mA |
| Output leakage current (Power-OFF) | I _{OPD} | V _{OUT} = 5.5 V | | 0 | | — | 0.5 | μΑ |

11.2. DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit |
|---|------------------|---|--|---------------------|------|-------|------|
| High-level input voltage | V _{IH} | _ | | 4.5 to 5.5 | 2.0 | _ | V |
| Low-level input voltage | V _{IL} | _ | | 4.5 to 5.5 | _ | 0.8 | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | 4.5 | 4.4 | _ | |
| | | | I _{OH} = -8 mA | 4.5 | 3.80 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50μA | 4.5 | _ | 0.1 | |
| | | | I _{OL} = 8 mA | 4.5 | _ | 0.44 | |
| 3-state output OFF-state leakage current | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND | | | — | ±2.50 | μA |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±1.0 | |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | V _{IN} = V _{CC} or GND | | _ | 40.0 | |
| Quiescent supply current | I _{CCT} | Per input: V _{IN} = 3.4 V other input: V _{CC} or GND | | 5.5 | — | 1.50 | mA |
| Output leakage current (Power-OFF) | I _{OPD} | V _{OUT} = 5.5 V | | 0 | _ | 5.0 | μA |

11.3. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Part Number | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Unit |
|-------------------------------|--------------|------------------------------------|----------|-----------------------|---------------------|---------------------|-----|------|------|------|
| Propagation delay time | 74VHCT540AFT | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | _ | 5.4 | 7.4 | ns |
| | | | | | | 50 | _ | 5.9 | 8.4 | |
| | 74VHCT541AFT | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | _ | 5.0 | 6.9 | |
| | | | | | | 50 | _ | 5.5 | 7.9 | |
| 3-state output enable time | | t _{PZL} ,t _{PZH} | | R _L = 1 kΩ | 5.0 ± 0.5 | 15 | _ | 8.3 | 11.3 | |
| | | | | | | 50 | _ | 8.8 | 12.3 | |
| 3-state output disable time | | t _{PLZ} ,t _{PHZ} | | R _L = 1 kΩ | 5.0 ± 0.5 | 50 | _ | 9.4 | 11.9 | |
| Output skew | | t_{osLH}, t_{osHL} | (Note 1) | _ | 5.0 ± 0.5 | 50 | _ | _ | 1.0 | |
| Input capacitance | | C _{IN} | | _ | | | _ | 4 | 10 | pF |
| Output capacitance | | C _{OUT} | | _ | | | _ | 9 | _ | |
| Power dissipation capacitance | | C _{PD} | (Note 2) | _ | | | | 19 | — | |

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLHm} - t_{PLHn}|, t_{osHL} = |t_{PHLm} - t_{PHLn}|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

11.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Part Number | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|-----------------------------|--------------|------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | 74VHCT540AFT | t _{PLH} ,t _{PHL} | | — | 5.0 ± 0.5 | 15 | 1.0 | 8.5 | ns |
| | | | | | | 50 | 1.0 | 9.5 | |
| | 74VHCT541AFT | t _{PLH} ,t _{PHL} | | _ | 5.0 ± 0.5 | 15 | 1.0 | 8.0 | |
| | | | | | | 50 | 1.0 | 9.0 | |
| 3-state output enable time | | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 15 | 1.0 | 13.0 | |
| | | | | | | 50 | 1.0 | 14.0 | |
| 3-state output disable time | | t _{PLZ} ,t _{PHZ} | | $R_L = 1 k\Omega$ | 5.0 ± 0.5 | 50 | 1.0 | 13.5 | |
| Output skew | | t_{osLH}, t_{osHL} | (Note 1) | _ | 5.0 ± 0.5 | 50 | _ | 1.0 | |
| Input capacitance | | C _{IN} | | _ | | | _ | 10 | рF |

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLHm} - t_{PLHn}|$, $t_{osHL} = |t_{PHLm} - t_{PHLn}|$)

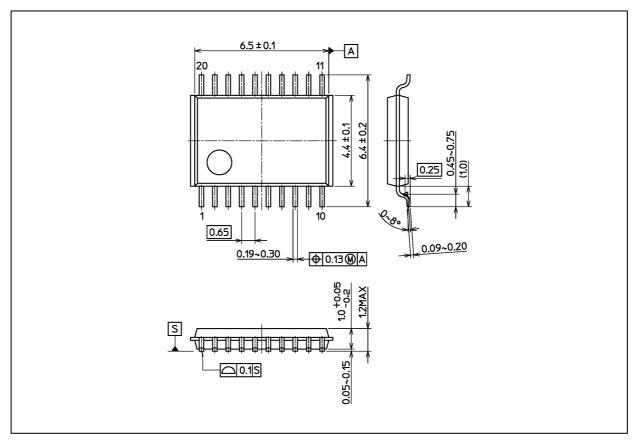
11.5. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Limit | Unit |
|--|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic V _{OL} | V _{OLP} | C _L = 50 pF | 5.0 | 1.1 | 1.5 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | C _L = 50 pF | 5.0 | -1.1 | -1.5 | |
| Minimum high-level dynamic input voltage | V _{IHD} | C _L = 50 pF | 5.0 | _ | 2.0 | |
| Maximum low-level dynamic input voltage | V _{ILD} | C _L = 50 pF | 5.0 | | 0.8 | |



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

| | Package Name(s) |
|--------------------|-----------------|
| Nickname: TSSOP20B | |

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